	o:i al No. of Questions: 09 [Total N	o. of Pages: 01]
100	MAY-2014	o. o. 1 ages. o. 1
	B. Tech. CSE(Sem. – 3 rd)	
DIGITAL CIRCUITS & LOGIC DESIGN (BTCS - 303) Time: 03 Hours Maximum Marks: 60		
1 11110	Instruction to Candidates:	iiuiii Marks . 00
	1) Section - A is Compulsory.	
	2) Attempt any Four questions from Section - B.	
	3) Attempt any Two questions from Section - C. Section - A	
Q1)	Section 71	(10x2=20)
	a). Find the signed 8-bit binary number equivalent to 7 ₁₀ .	
	b). How many AND gates are required to realize $Y = ACD + EF + C$	GH
	c). What is the difference between synchronous and asynchronous?	
	d). What do you understand by nonvolatile memory?	20
	e). What is the use of EEPROM?	QO.
	f). Write the name of various types of Digital to Analog Convertors	
	g). What is the difference between edge triggering and level trigger	ing?
	h). What is the use of static RAM?	
	i). Define racing problem in JK-Flip flop.	
	j). Write one advantage of CMOS logic family.	
	Section – B	(4x5=20)
Q2)	State and prove De-Morgan's theorems.	
Q3)	Draw and explain the operation of TTL inverter.	
Q4)	Implement the function $f(w, x, y, z) = m(0, 1, 5, 7, 8, 10, 13, 14, 15)$	using two 8-way
	multiplexers with an active low enable, plus an OR gate.	
Q5)	Explain the working of ladder type Digital to Analog Convertor.	
Q6)	Write a short note on Field Programmable Gate Array.	
	Section – C	(2x10=20)
Q7)	Find the minimum sum of products expression for the function	

 $f(a, b, c, d) = \sum m(1, 3, 4, 6, 7, 9, 11, 12, 13, 15)$ using QM method.

Q8) Design a MOD - 10 synchronous counter using J-K Flip-Flops. Explain its working with the help of timing diagram.

Q9) Discuss various types of Read only Memories in detail.

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